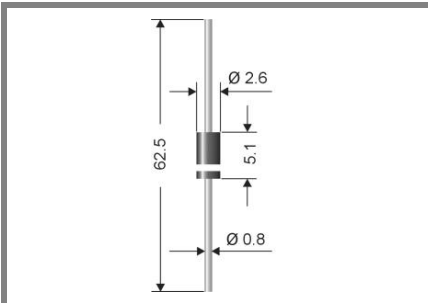


# EM 513, EM 516, EM 518



## Axial lead diode

### Standard silicon rectifier diodes

EM 513, EM 516, EM 518

Forward Current: 1 A

Reverse Voltage: 1600 to 2000 V

### Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

### Mechanical Data

- Plastic case DO-41 / DO-204AL
- Weight approx.: 0.4 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 5000 pieces per ammo

1) Valid, if leads are kept at ambient temperature at a distance of 10 mm from case

2)  $I_F = 1A$ ,  $T_j = 25^\circ C$

3)  $T_A = 25^\circ C$

| Type   | Repetitive peak reverse voltage<br>$V_{RRM}$<br>V | Surge peak reverse voltage<br>$V_{RSM}$<br>V | Max. reverse recovery time<br>$I_F = -A$<br>$I_R = -A$<br>$I_{RR} = -A$<br>$t_{rr}$<br>ns | Max. forward voltage<br>$V_F^{2)}$ |
|--------|---|--|---|------------------------------------|
| EM 513 | 1600  | 1600   | -   | 1,1                                |
| EM 516 | 1800  | 1800   | -   | 1,1                                |
| EM 518 | 2000  | 2000   | -   | 1,1                                |

### Absolute Maximum Ratings

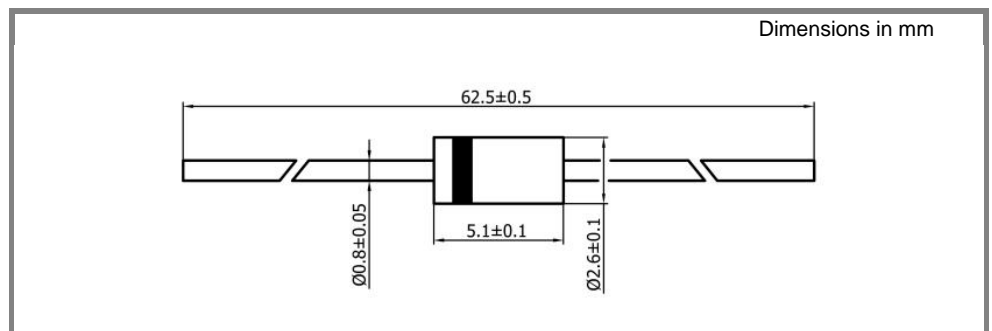
$T_c = 25^\circ C$ , unless otherwise specified

| Symbol    | Conditions   | Values     | Units            |
|-----------|--|------------|------------------|
| $I_{FAV}$ | Max. averaged fwd. current, R-load, $T_A = 75^\circ C$ <sup>1)</sup> | 1          | A                |
| $I_{FRM}$ | Repetitive peak forward current $f > 15 Hz$ <sup>1)</sup>            | 10         | A                |
| $I_{FSM}$ | Peak forward surge current 50 Hz half sinus-wave <sup>3)</sup>       | 50         | A                |
| $i^2t$    | Rating for fusing, $t < 10 ms$ <sup>3)</sup>                         | 12,5       | A <sup>2</sup> s |
| $R_{thA}$ | Max. thermal resistance junction to ambient <sup>1)</sup>            | 45         | K/W              |
| $R_{thT}$ | Max. thermal resistance junction to terminals <sup>1)</sup>          | -          | K/W              |
| $T_j$     | Operating junction temperature                                       | -50...+175 | °C               |
| $T_s$     | Storage temperature  | -50...+175 | °C               |

### Characteristics

$T_c = 25^\circ C$ , unless otherwise specified

| Symbol    | Conditions   | Values | Units   |
|-----------|--|--------|---------|
| $I_R$     | Maximum leakage current, $T_j = 25^\circ C$ ; $V_R = V_{RRM}$  | <5     | $\mu A$ |
|           | $T_j = 100^\circ C$ ; $V_R = V_{RRM}$  | <50    | $\mu A$ |
| $C_j$     | Typical junction capacitance<br>(at MHz and applied reverse voltage of V)                                      | -      | pF      |
| $Q_{rr}$  | Reverse recovery charge<br>( $U_R = V$ ; $I_F = A$ ; $dI_F/dt = A/ms$ )  | -      | $\mu C$ |
| $E_{RSM}$ | Non repetitive peak reverse avalanche energy<br>( $I_R = mA$ ; $T_j = ^\circ C$ ; inductive load switched off) | -      | mJ      |



case: DO-41 / DO-204AL

